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Kind regards,

Team Nexperia

# 1PSxSB17

# 4 V, 30 mA low C<sub>d</sub> Schottky barrier diode Rev. 06 — 4 April 2005

**Product data sheet** 

#### **Product profile** 1.

# 1.1 General description

Planar low capacitance Schottky barrier diode encapsulated in a very small SMD plastic package.

Table 1: **Product overview** 

| Type number | Package |       | Configuration         |
|-------------|---------|-------|-----------------------|
|             | Philips | JEITA |                       |
| 1PS66SB17   | SOT666  | -     | triple isolated diode |
| 1PS76SB17   | SOD323  | SC-76 | single diode          |
| 1PS79SB17   | SOD523  | SC-79 | single diode          |

#### 1.2 Features

- Very low diode capacitance
- Very low forward voltage
- Very small SMD plastic packages

# 1.3 Applications

- Digital applications:
  - Ultra high-speed switching
  - Clamping circuits.
- RF applications:
  - Diode ring mixer
  - RF detector
  - ◆ RF voltage doubler

#### 1.4 Quick reference data

Table 2: **Quick reference data** 

| Symbol         | Parameter                  | Conditions | Min | Тур | Max | Unit |
|----------------|----------------------------|------------|-----|-----|-----|------|
| I <sub>F</sub> | continuous forward current |            | -   | -   | 30  | mA   |
| $V_R$          | continuous reverse voltage |            | -   | -   | 4   | V    |
| $C_d$          | diode capacitance          |            | -   | 8.0 | 1   | pF   |



# 2. Pinning information

Table 3: Pinning

| Table 5.  | 1 111111119            |                    |   |
|-----------|------------------------|--------------------|---|
| Pin       | Description            | Simplified outline | Symbol  |
| SOD323 (S | SC-76); SOD523 (SC-79) |                    |   |
| 1         | cathode                | [1]                |   |
| 2         | anode                  | 001aab540          | 1 <del>【                                   </del> |
| SOT666    |                        |                    |   |
| 1         | anode (diode 1)        |                    |   |
| 2         | anode (diode 2)        | 6 5 4              | 6 5 4   |
| 3         | anode (diode 3)        |                    |   |
| 4         | cathode (diode 3)      |                    | 1 2 3   |
| 5         | cathode (diode 2)      |                    | sym046  |
|           |                        |                    |   |

<sup>[1]</sup> The marking bar indicates the cathode.

cathode (diode 1)

# 3. Ordering information

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**Table 4: Ordering information** 

| Type number | Package | Package                                  |         |  |  |  |
|-------------|---------|--|---------|--|--|--|
|             | Name    | Description                              | Version |  |  |  |
| 1PS66SB17   | -       | plastic surface mounted package; 6 leads | SOT666  |  |  |  |
| 1PS76SB17   | SC-76   | plastic surface mounted package; 2 leads | SOD323  |  |  |  |
| 1PS79SB17   | SC-79   | plastic surface mounted package; 2 leads | SOD523  |  |  |  |

# 4. Marking

Table 5: Marking codes

| Type number | Marking code |
|-------------|--------------|
| 1PS66SB17   | N2           |
| 1PS76SB17   | S7           |
| 1PS79SB17   | T2           |

# 5. Limiting values

Table 6: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol         | Parameter                  | Conditions | Min | Max | Unit |
|----------------|----------------------------|------------|-----|-----|------|
| $V_R$          | continuous reverse voltage |            | -   | 4   | V    |
| I <sub>E</sub> | continuous forward current |            | -   | 30  | mA   |

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 Table 6:
 Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter            | Conditions | Min | Max  | Unit |
|------------------|----------------------|------------|-----|------|------|
| Tj               | junction temperature |            | -   | 150  | °C   |
| T <sub>amb</sub> | ambient temperature  |            | -65 | +150 | °C   |
| T <sub>stg</sub> | storage temperature  |            | -65 | +150 | °C   |

# 6. Thermal characteristics

Table 7: Thermal characteristics

| Symbol  | Parameter | Conditions  | Min        | Тур | Max | Unit |
|---|-----------|-------------|------------|-----|-----|------|
| R <sub>th(j-a)</sub> thermal resistance from junction to ambient; |           | in free air | <u>[1]</u> |     |     |      |
|   | SOD323    |             | [2] _      | -   | 450 | K/W  |
|   | SOD523    |             | [3] _      | -   | 450 | K/W  |
|   | SOT666    |             | [4] _      | -   | 700 | K/W  |

<sup>[1]</sup> For Schottky barrier diodes, thermal run-away has to be considered as in some applications the reverse power losses  $P_R$  are a significant part of the total power losses. Nomograms for determining the reverse power losses  $P_R$  and  $I_{F(AV)}$  rating will be available on request.

# 7. Characteristics

**Table 8: Characteristics** 

 $T_{amb} = 25 \,^{\circ}C$  unless otherwise specified.

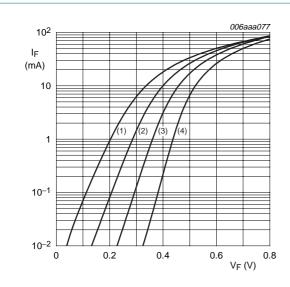
| Symbol         | Parameter       | Conditions                               | Min        | Тур  | Max | Unit |
|----------------|-----------------|--|------------|------|-----|------|
| $V_{F}$        | forward voltage | see Figure 1;                            | <u>[1]</u> |      |     |      |
|                |                 | $I_F = 0.1 \text{ mA}$                   | -          | 300  | 350 | mV   |
|                |                 | $I_F = 1 \text{ mA}$                     | -          | 360  | 450 | mV   |
|                |                 | I <sub>F</sub> = 10 mA                   | -          | 470  | 600 | mV   |
| I <sub>R</sub> | reverse current | V <sub>R</sub> = 3 V; see Figure 2       | -          | -    | 250 | nA   |
| C <sub>d</sub> | diode           | see Figure 3;                            |            |      |     |      |
|                | capacitance     | V <sub>R</sub> = 0 V; f = 1 MHz          | -          | 0.8  | 1   | pF   |
|                |                 | $V_R = 0.5 \text{ V}; f = 1 \text{ MHz}$ | -          | 0.65 | -   | pF   |

<sup>[1]</sup> Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .

<sup>[2]</sup> Refer to SOD323 (SC-76) standard mounting conditions.

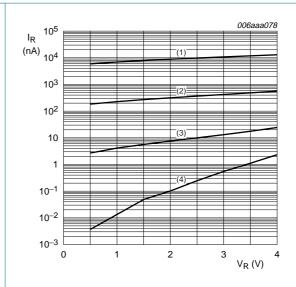
<sup>[3]</sup> Refer to SOD523 (SC-79) standard mounting conditions.

<sup>[4]</sup> Refer to SOT666 standard mounting conditions.



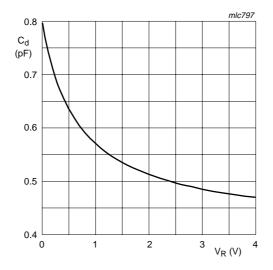
- (1)  $T_{amb} = 150 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$
- (4)  $T_{amb} = -40 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values.



- (1)  $T_{amb} = 150 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$
- (4)  $T_{amb} = -40 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values.



 $T_{amb} = 25 \,^{\circ}\text{C}$ ;  $f = 1 \, \text{MHz}$ 

Fig 3. Diode capacitance as a function of reverse voltage; typical values.

# 8. Package outline

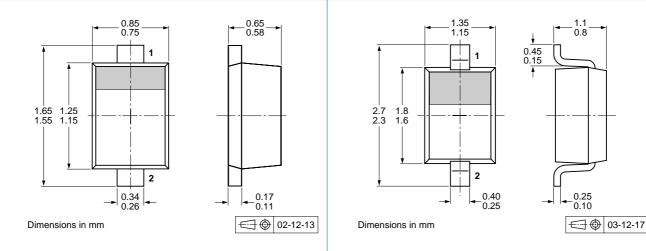


Fig 4. Package outline SOD523 (SC-79)



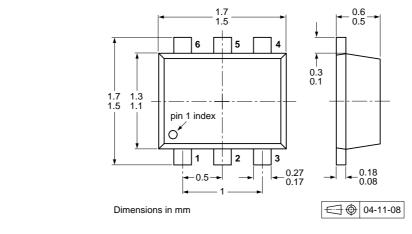


Fig 6. Package outline SOT666

# 9. Packing information

#### Table 9: Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code. [1]

| Type number | Package | Description                    | Packing quantity |      |       |
|-------------|---------|--------------------------------|------------------|------|-------|
|             |         |                                | 3000             | 4000 | 10000 |
| 1PS66SB17   | SOT666  | 4 mm pitch, 8 mm tape and reel | -                | -115 | -     |
| 1PS76SB17   | SOD323  | 4 mm pitch, 8 mm tape and reel | -115             |      | -135  |
| 1PS79SB17   | SOD523  | 4 mm pitch, 8 mm tape and reel | -115             |      | -135  |

<sup>[1]</sup> For further information and the availability of packing methods, see Section 14.

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# 10. Revision history

# Table 10: Revision history

| Document ID           | Release date                  | Data sheet status      | Change notice | Doc. number    | Supersedes                |
|-----------------------|-------------------------------|------------------------|---------------|----------------|---------------------------|
| 1PSXSB17_6            | 20050404                      | Product data sheet     | -             | 9397 750 14587 | 1PS76SB17_1<br>PS79SB17_5 |
| Modifications:        | <ul> <li>Type numl</li> </ul> | oer 1PS66SB17 added    |               |                |                           |
| 1PS76SB17_1PS79SB17_5 | 20041028                      | Product data sheet     | -             | 9397 750 13733 | 1PS76SB17_4               |
| 1PS76SB17_4           | 20040126                      | Product data sheet     | -             | 9397 750 12618 | 1PS76SB17_3               |
| 1PS76SB17_3           | 20020809                      | Product data sheet     | -             | 9397 750 10174 | 1PS76SB17_2               |
| 1PS76SB17_2           | 19990525                      | Preliminary data sheet | -             | 9397 750 05893 | 1PS76SB17_1               |
| 1PS76SB17_1           | 19961014                      | Preliminary data sheet | -             | 9397 750 01342 | -                         |

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### 11. Data sheet status

| Level | Data sheet status [1] | Product status [2] [3] | Definition   |
|-------|-----------------------|------------------------|--|
| I     | Objective data        | Development            | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.  |
| II    | Preliminary data      | Qualification          | This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.             |
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- [1] Please consult the most recently issued data sheet before initiating or completing a design.
- [2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- [3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

#### 12. Definitions

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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4 V, 30 mA low C<sub>d</sub> Schottky barrier diode

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Date of release: 4 April 2005 Document number: 9397 750 14587

